74LVC821A

10-bit D-type flip-flop with 5 V tolerant inputs/outputs; positive-edge trigger; 3-state

Rev. 4 — 23 November 2012

Product data sheet

1. General description

The 74LVC821A is a 10-bit D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-state outputs for bus-oriented applications. A clock input (pin CP) and an output enable input (pin $\overline{\text{OE}}$) are common to all flip-flops. The ten flip-flops store the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW-to-HIGH CP transition. When pin $\overline{\text{OE}}$ is LOW, the contents of the ten flip-flops are available at the outputs.

When pin \overline{OE} is HIGH, the outputs go to the high-impedance OFF-state. Operation of the \overline{OE} inputs does not affect the state of the flip-flops.

Inputs can be driven from either 3.3 V or 5 V devices. When disabled, up to 5.5 V can be applied to the outputs. These features allow the use of these devices as translators in mixed 3.3 V and 5 V applications.

2. Features and benefits

- 5 V tolerant inputs and outputs; for interfacing with 5 V logic
- Wide supply voltage range from 1.2 V to 3.6 V
- CMOS low power consumption
- Direct interface with TTL levels
- Flow-through pinout architecture
- 10-bit positive edge-triggered register
- Independent register and 3-state buffer operation
- Complies with JEDEC standard:
 - ◆ JESD8-7A (1.65 V to 1.95 V)
 - ◆ JESD8-5A (2.3 V to 2.7 V)
 - ◆ JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-B exceeds 200 V
 - ◆ CDM JESD22-C101E exceeds 1000 V
- Specified from −40 °C to +85 °C and −40 °C to +125 °C.



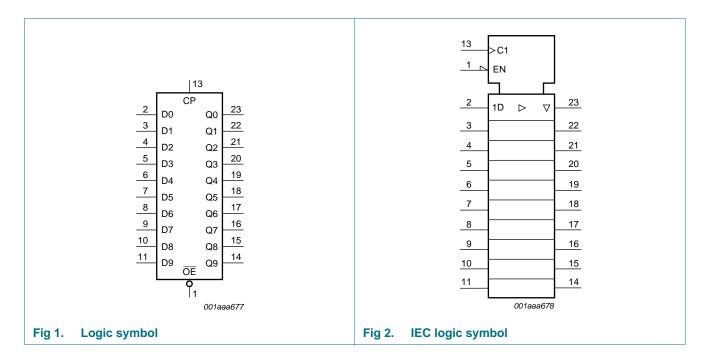
10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state

3. Ordering information

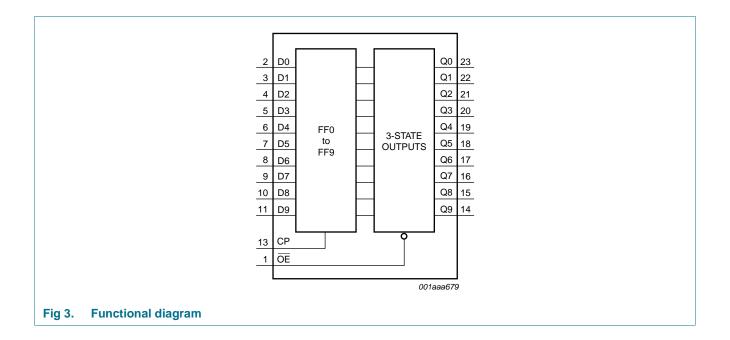
Table 1. Ordering information

Type number	Package	Package												
	Temperature range	Name	Description	Version										
74LVC821AD	–40 °C to +125 °C	SO24	plastic small outline package; 24 leads; body width 7.5 mm	SOT137-1										
74LVC821ADB	–40 °C to +125 °C	SSOP24	plastic shrink small outline package; 24 leads; body width 5.3 mm	SOT340-1										
74LVC821APW	–40 °C to +125 °C	TSSOP24	plastic thin shrink small outline package; 24 leads; body width 4.4 mm	SOT355-1										
74LVC821ABQ	–40 °C to +125 °C	DHVQFN24	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body $3.5\times5.5\times0.85$ mm	SOT815-1										

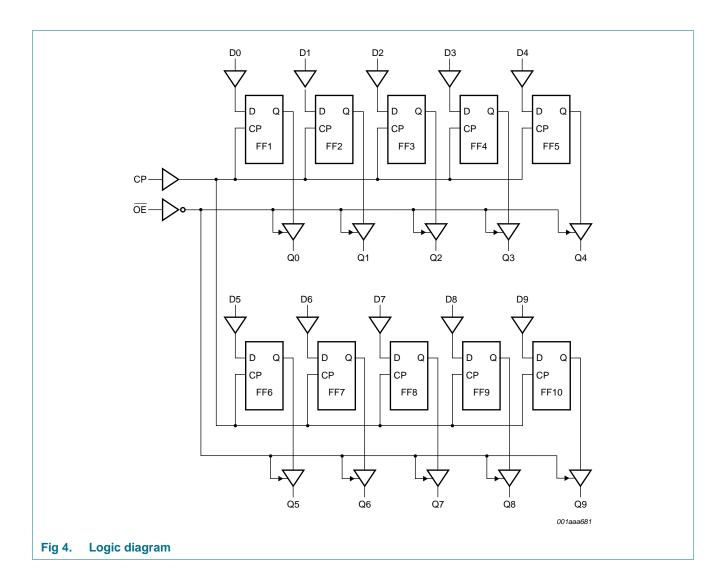
4. Functional diagram



10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state



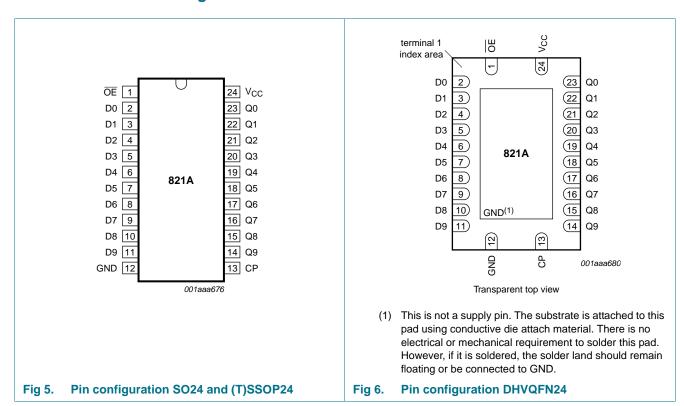
10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state



10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
OE	1	output enable input (active LOW)
СР	13	clock input (LOW-to-HIGH, edge-triggered)
D[0:9]	2, 3, 4, 5, 6, 7, 8, 9, 10, 11	data input
Q[0:9]	23, 22, 21, 20, 19, 18, 17, 16, 15, 14	3-state flip-flop output
GND	12	ground (0 V)
V _{CC}	24	supply voltage

10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state

6. Functional description

Table 3. Function table[1]

Operating mode	Input		Internal	Output	
	OE	СР	Dn	flip-flops	Qn
Load and read register	L	↑	I	L	L
	L	↑	h	Н	Н
Load register and disable outputs	Н	↑	I	L	Z
	Н	↑	h	Н	Z
Hold	L	H or L	Х	NC	NC

^[1] H = HIGH voltage level

h = HIGH voltage level one set-up time before the LOW-to-HIGH CP transition

L = LOW voltage level

I = LOW voltage level one set-up time before the LOW-to-HIGH CP transition

Z = high-impedance OFF-state

↑ = LOW-to-HIGH clock transition

X = don't care

NC = no change

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage		[<u>1</u>] -0.5	+6.5	V
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0 V$	-	±50	mA
Vo	output voltage	HIGH or LOW state	[2] -0.5	$V_{CC} + 0.5$	V
		3-state	[2] -0.5	+6.5	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±50	mA
I _{CC}	supply current		-	100	mA
I_{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C	[3]	500	mW

^[1] The minimum input voltage ratings may be exceeded if the input current ratings are observed.

^[2] The output voltage ratings may be exceeded if the output current ratings are observed.

^[3] For SO24 package: above 70 °C derate linearly with 8 mW/K.
For SSOP24 and TSSOP24 packages: above 60 °C derate linearly with 5.5 mW/K.
For DHVQFN24 package: above 60 °C derate linearly with 4.5 mW/K.

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8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		1.65	-	3.6	V
		functional	1.2	-	-	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	HIGH or LOW state	0	-	V_{CC}	V
		3-state	0	-	5.5	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
Δt/ΔV	input transition rise and fall	$V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$	0	-	20	ns/V
	rate	V _{CC} = 2.7 V to 3.6 V	0	-	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	35 °C	-40 °C to	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level	V _{CC} = 1.2 V	1.08	-	-	1.08	-	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$	-	-	$0.65 \times V_{CC}$	-	V
		V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
V _{IL} LOW-level		V _{CC} = 1.2 V	-	-	0.12	-	0.12	V
input voltage	input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	$0.35 \times V_{CC}$	-	$0.35 \times V_{CC}$	V
	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	-	0.7	-	0.7	V	
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}						
	output voltage	$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	V _{CC} - 0.2	-	-	$V_{CC}-0.3$	-	V
		$I_O = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	1.05	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.8	-	-	1.65	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	2.05	-	V
		$I_{O} = -18 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	-	-	2.25	-	٧
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.2	-	-	2.0	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}						
	output voltage	$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	-	-	0.2	-	0.3	V
		$I_O = 4 \text{ mA}$; $V_{CC} = 1.65 \text{ V}$	-	-	0.45	-	0.65	V
		$I_{O} = 8 \text{ mA}$; $V_{CC} = 2.3 \text{ V}$	-	-	0.6	-	0.8	٧
		$I_O = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.4	-	0.6	٧
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	-	0.8	٧
I _I	input leakage current	$V_{CC} = 3.6 \text{ V}; V_{I} = 5.5 \text{ V or GND}$	-	±0.1	±5	-	±20	μΑ

10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state

Table 6. Static characteristics ... continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		-40	°C to +8	85 °C	–40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
I _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 3.6$ V; $V_O = 5.5$ V or GND;	-		0.1	±5	-	±20	μΑ
I _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}$; $V_I \text{ or } V_O = 5.5 \text{ V}$	-		0.1	±10	-	±20	μΑ
I _{CC}	supply current	$V_{CC} = 3.6 \text{ V}; V_I = V_{CC} \text{ or GND};$ $I_O = 0 \text{ A}$	-		0.1	10	-	40	μΑ
ΔI_{CC}	additional supply current	per input pin; $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V};$ $V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}$	-		5	500	-	5000	μΑ
C _I	input capacitance	$V_{CC} = 0 \text{ V to } 3.6 \text{ V};$ $V_{I} = \text{GND to } V_{CC}$	-		5.0	-	-	-	pF

^[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 10.

Symbol	Parameter	Conditions		$T_{amb} =$	–40 °C to	+85 °C	-40 °C to	Unit	
				Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation	CP to Qn; see Figure 7	[2]						
	delay	V _{CC} = 1.2 V		-	18	-	-	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		2.4	8.6	17.1	2.3	19.7	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.8	4.5	8.8	1.6	10.1	ns
		$V_{CC} = 2.7 \text{ V}$		1.5	4.1	8.5	2.2	11.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	3.8	7.3	2.0	9.5	ns
t _{en}	enable time	OE to Qn; see Figure 9	[2]						
		V _{CC} = 1.2 V		-	20	-	-	-	ns
		V _{CC} = 1.65 V		1.8	7.7	17.4	1.6	20.1	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.5	4.3	9.6	1.3	11.0	ns
		$V_{CC} = 2.7 \text{ V}$		1.3	4.4	8.8	2.4	11.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	3.5	7.6	1.5	9.5	ns
t _{dis}	disable time	OE to Qn; see Figure 9	[2]						
		V _{CC} = 1.2 V		-	9.0	-	-	-	ns
		V _{CC} = 1.65 V		2.5	4.4	10.4	1.8	12.0	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.0	2.4	5.9	0.6	6.8	ns
		$V_{CC} = 2.7 \text{ V}$		1.5	3.3	6.8	2.2	8.5	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	3.0	6.2	1.9	8.0	ns

10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 10.

Symbol	Parameter	Conditions	T	amb =	–40 °C to	+85 °C	-40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _W	pulse width	clock HIGH or LOW; see Figure 7							
		V _{CC} = 1.65 V to 1.95 V		5.0	-	-	5.0	-	ns
		V_{CC} = 2.3 V to 2.7 V		4.0	-	-	4.0	-	ns
		V _{CC} = 2.7 V		3.3	-	-	3.3	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		3.3	1.7	-	3.3	-	ns
t _{su}	set-up time	Dn to CP; see Figure 8							
		V _{CC} = 1.65 V to 1.95 V		3.5	-	-	3.5	-	ns
		V_{CC} = 2.3 V to 2.7 V		2.0	-	-	2.0	-	ns
		V _{CC} = 2.7 V		0.9	-	-	0.9	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.9	0.6	-	1.9	-	ns
t _h	hold time	Dn to CP; see Figure 8							
		V _{CC} = 1.65 V to 1.95 V		3.0	-	-	3.0	-	ns
		V_{CC} = 2.3 V to 2.7 V		2.0	-	-	2.0	-	ns
		V _{CC} = 2.7 V		1.5	-	-	1.5	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	0.0	-	1.5	-	ns
f _{max}	maximum	see Figure 7							
	frequency	V _{CC} = 1.65 V to 1.95 V		100	-	-	80	-	MHz
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		125	-	-	100	-	MHz
		V _{CC} = 2.7 V		150	-	-	120	-	MHz
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		150	200	-	120	-	MHz
t _{sk(o)}	output skew time	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	-	1.0	-	1.5	ns
C _{PD}	power	per input; $V_I = GND$ to V_{CC}	<u>[4]</u>						
	dissipation	V _{CC} = 1.65 V to 1.95 V		-	12.5	-	-	-	pF
	capacitance	V_{CC} = 2.3 V to 2.7 V		-	14.7	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V		-	16.6	-	-	-	pF

^[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.2 V, 1.8 V, 2.5 V, 2.7 V and 3.3 V respectively.

 t_{dis} is the same as t_{PLZ} and t_{PHZ} .

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz; f_o = output frequency in MHz

 C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$ = sum of the outputs

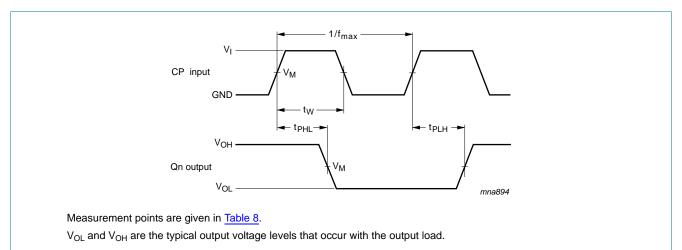
^[2] t_{pd} is the same as t_{PLH} and t_{PHL} . t_{en} is the same as t_{PZL} and t_{PZH} .

^[3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

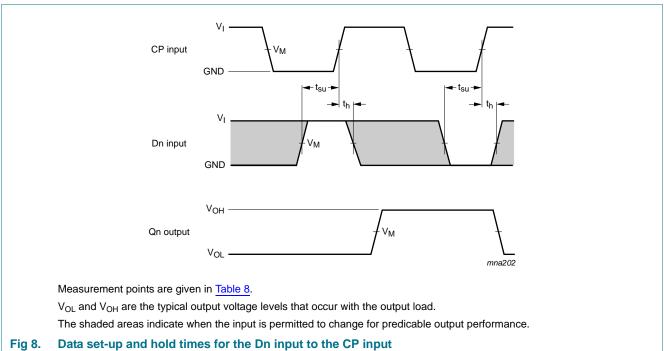
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11. Waveforms



Clock (CP) to output (Qn) propagation delays, the clock pulse width, and the maximum frequency Fig 7.



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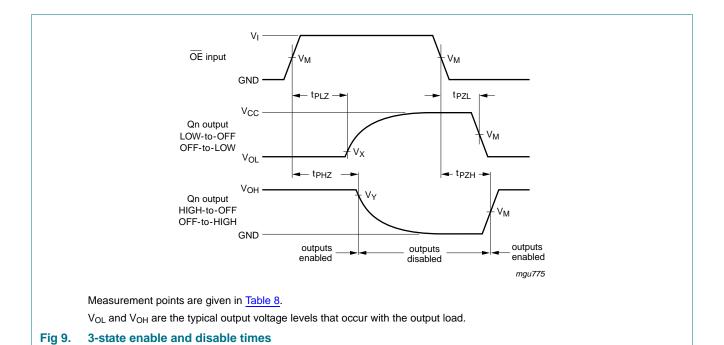
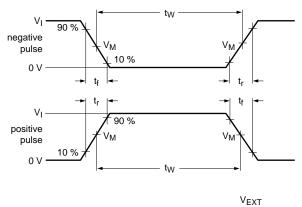
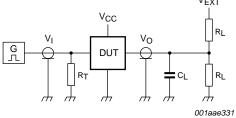


Table 8. Measurement points

Supply voltage	Input		Output							
V _{CC}	VI	V _M	V _M	V _X	V _Y					
1.2 V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V _{OL} + 0.15 V	$V_{OH}-0.15\ V$					
1.65 V to 1.95 V	V_{CC} 0.5 × V_{CC}		$0.5 \times V_{CC}$	V _{OL} + 0.15 V	$V_{OH}-0.15~V$					
2.3 V to 2.7 V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V _{OL} + 0.15 V	$V_{OH}-0.15~V$					
2.7 V	2.7 V	1.5 V	1.5 V	V _{OL} + 0.3 V	$V_{OH}-0.3\ V$					
3.0 V to 3.6 V	2.7 V 1.5 V		1.5 V	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$					

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Test data is given in Table 9.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 10. Load circuitry for switching times

Table 9. Test data

Supply voltage	Input		Load		V _{EXT}	V _{EXT}			
	VI	t _r , t _f	CL	R_L	t _{PLH} , t _{PHL}	t_{PLZ}, t_{PZL}	t _{PHZ} , t _{PZH}		
1.2 V	V_{CC}	≤ 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND		
1.65 V to 1.95 V	V_{CC}	≤ 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND		
2.3 V to 2.7 V	V_{CC}	≤ 2 ns	30 pF	500Ω	open	$2\times V_{CC}$	GND		
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500Ω	open	$2 \times V_{CC}$	GND		
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500Ω	open	$2\times V_{CC}$	GND		

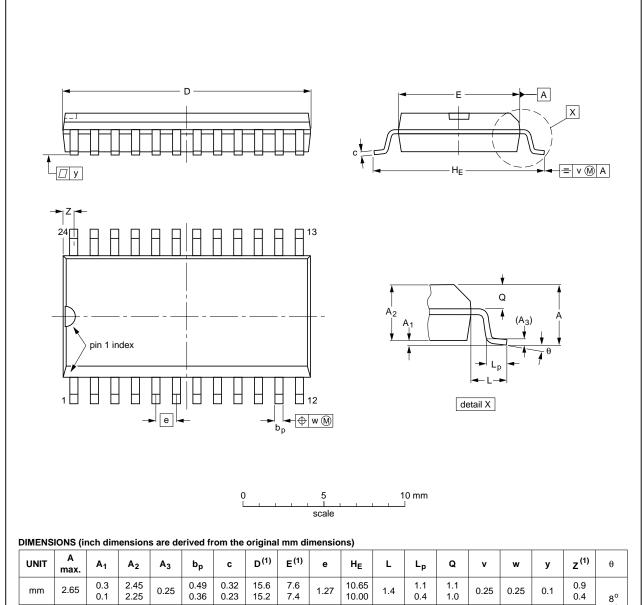
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12. Package outline

SO24: plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	15.6 15.2	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.61 0.60	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE			REFER	ENCES	EUROPEAN	ISSUE DATE		
	VERSION	IEC	JEDEC	JEITA	PROJECTION	1330E DATE		
	SOT137-1	075E05	MS-013			-99-12-27 03-02-19		

Fig 11. Package outline SOT 137-1 (SO24)

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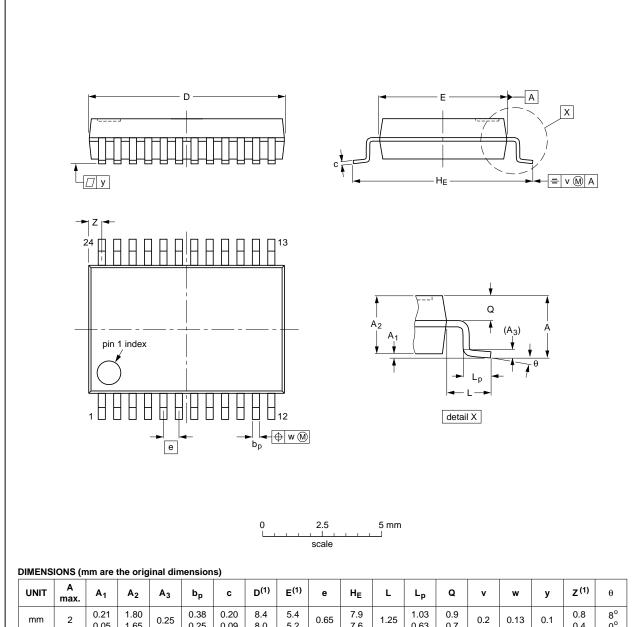
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10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state

SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm

SOT340-1



Ξ							-,												
	UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
	mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	8.4 8.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.8 0.4	8° 0°

Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT340-1		MO-150			99-12-27 03-02-19	
					03-02-19	

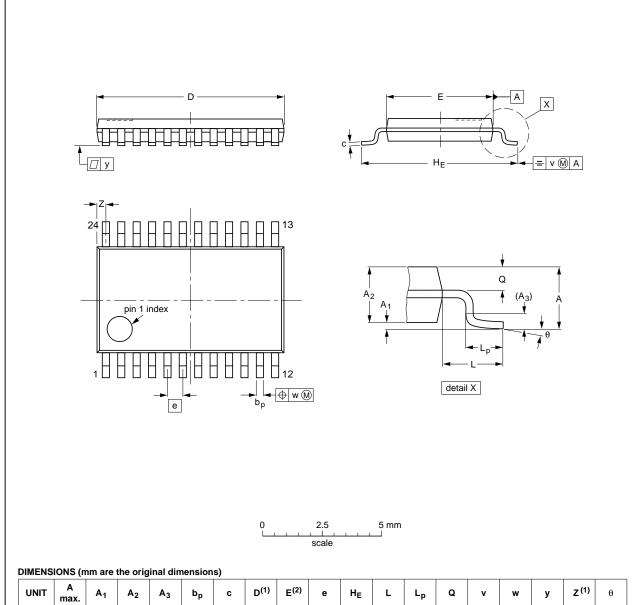
Fig 12. Package outline SOT 340-1 (SSOP24)

74LVC821A

10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state

TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	C	D ⁽¹⁾	E ⁽²⁾	e	HE	L	Lp	Q	٧	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	7.9 7.7	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT355-1		MO-153			99-12-27 03-02-19	
				1	03-02-19	

Fig 13. Package outline SOT 355-1 (TSSOP24)

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10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state

DHVQFN24: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body $3.5 \times 5.5 \times 0.85$ mm

SOT815-1

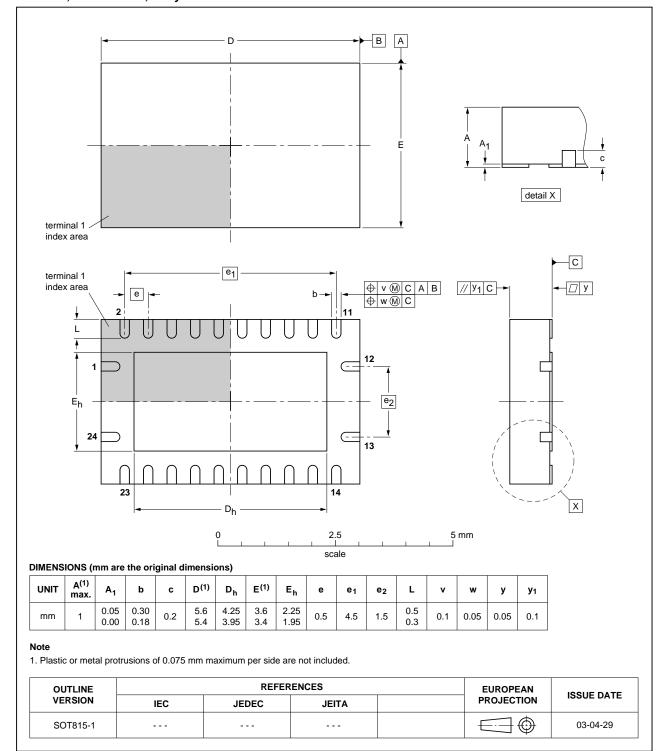


Fig 14. Package outline SOT 815-1 (DHVQFN24)

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10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC821A v.4	20121123	Product data sheet	-	74LVC821A v.3
Modifications:	 The format of of NXP Semice 	this data sheet has been red conductors.	esigned to comply with	n the new identity guidelines
	 Legal texts ha 	ive been adapted to the new	company name where	appropriate.
	• Table 4, Table	5, Table 6, Table 7, and Tab	le 8: values added for	lower voltage ranges.
74LVC821A v.3	20040511	Product specification	-	74LVC821A v.2
74LVC821A v.2	20040415	Product specification	-	74LVC821A v.1
74LVC821A v.1	19980925	Product specification	-	-

10-bit D-type flip-flop; 5 V tolerance; positive-edge trigger; 3-state

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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